

## FEATURES

High accuracy over line and load

$\pm 0.7\%$  at  $+25^\circ\text{C}$

$\pm 1.4\%$  over temperature

Ultralow dropout voltage: 140 mV (typical) at 200 mA

Requires only  $C_{OUT} = 0.47\ \mu\text{F}$  for stability

anyCAP = stable with any type of capacitor, including  
multilayer ceramic capacitors (MLCC)

Current and thermal limiting

Low noise

Low shutdown current:  $< 2\ \mu\text{A}$

2.9 V to 12 V supply range

$-40^\circ\text{C}$  to  $+85^\circ\text{C}$  ambient temperature range

Ultrasmall, thermally enhanced, chip-on-lead™ 6-lead SOT-23  
package

## APPLICATIONS

Cell phones

Notebook and palmtop computers

Battery-powered systems

PCMCIA regulators

Bar code scanners

Camcorders and cameras

## GENERAL DESCRIPTION

The **ADP3330** is a member of the Analog Devices, Inc., precision low dropout (LDO) anyCAP® voltage regulator family of products. The **ADP3330** operates with an input voltage range of 2.9 V to 12 V and delivers a load current up to 200 mA. The **ADP3330** stands out from the conventional LDOs with a novel architecture and an enhanced process that enables it to offer performance advantages and higher output current than its competition. Its patented design requires only a minimum output capacitor of  $0.47\ \mu\text{F}$  for stability. This device is insensitive to output capacitor equivalent series resistance (ESR), and is stable with any good quality capacitor, including ceramic (MLCC) types for space restricted applications. The **ADP3330** achieves exceptional accuracy of  $\pm 0.7\%$  at room temperature and  $\pm 1.4\%$  over temperature, line and load variations. The dropout voltage of the **ADP3330** is only 140 mV (typical) at 200 mA. This device also includes a safety current limit, thermal overload protection, and a shutdown feature. In shutdown mode, the ground current is

## SIMPLIFIED FUNCTIONAL BLOCK DIAGRAM

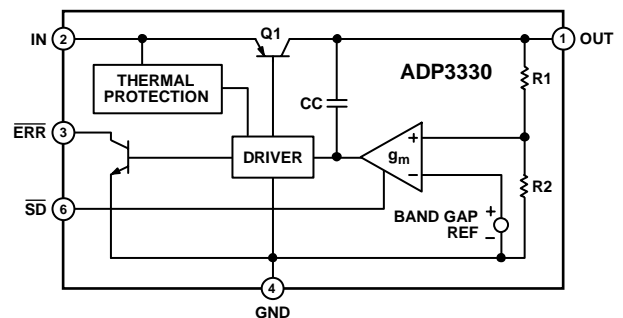


Figure 1.

12088-001

reduced to less than  $2\ \mu\text{A}$ . The **ADP3330** has an ultralow ground current  $34\ \mu\text{A}$  (typical) in light load situations.

The 6-lead SOT-23 package has been thermally enhanced using Analog Devices proprietary chip-on-lead feature to maximize power dissipation.

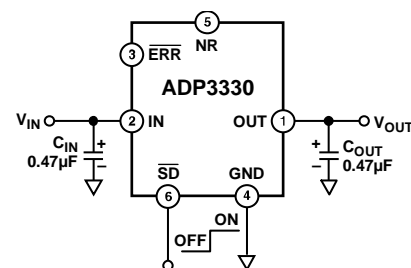


Figure 2. Typical Application Circuit

12088-002

# ADP3330\* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

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## COMPARABLE PARTS

View a parametric search of comparable parts.

## DOCUMENTATION

### Application Notes

- AN-1072: How to Successfully Apply Low Dropout Regulators
- AN-262: Low-Noise Low Drop-Out Regulator for Portable Equipment
- AN-349: Keys to Longer Life for CMOS
- AN-602: Using the ADXL202 in Pedometer and Personal Navigation Applications
- AN-900: Enhancing the Performance of Pedometers Using a Single Accelerometer

### Data Sheet

- ADP3330: High Accuracy, Ultralow I(Q), 200 mA, SOT-23, anyCAP Low Dropout Regulator Data Sheet

### Evaluation Kit Manuals

- EVAL-ADP3330/ADP3331

## TOOLS AND SIMULATIONS

- ADI Linear Regulator Design Tool and Parametric Search
- ADIsimPower™ Voltage Regulator Design Tool

## REFERENCE DESIGNS

- CN0031
- CN0158

## DESIGN RESOURCES

- ADP3330 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## DISCUSSIONS

View all ADP3330 EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

## TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

## DOCUMENT FEEDBACK

Submit feedback for this data sheet.

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## REVISION HISTORY

### 5/15—Rev. B to Rev. C

Changes to General Description Section .....	1
Changes to Chip-On-Lead Package Section .....	11
Changes to Ordering Guide .....	14

### 5/14—Rev. A to Rev. B

Updated Format.....	Universal
Changed 0.47 mF to 0.47 $\mu$ F, Features Section .....	1
Changes to General Description Section .....	1
Changed -2.5 V to 2.5 V, ADP3330-xx Section .....	3
Changes to Table 1.....	3
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Changes to Figure 16, Figure 17, and Figure 19 Caption.....	9
Changes to Printed Circuit Board (PCB) Layout Considerations Section, and Low Power, Low Dropout Applications Section..	12
Updated Outline Dimensions.....	14
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### 8/99—Rev. 0 to Rev. A

## SPECIFICATIONS

## ADP3330

At  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{IN} = 7\text{ V}$ ,  $C_{IN} = 0.47\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.47\text{ }\mu\text{F}$ , unless otherwise noted. Ambient temperature of  $85^{\circ}\text{C}$  corresponds to a junction temperature of  $125^{\circ}\text{C}$  under typical full load test conditions. Application stable with no load. The following specifications apply to all voltage options except 2.5 V.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
OUTPUT VOLTAGE ACCURACY	$V_{OUT}$	$V_{IN} = V_{OUTNOM} + 0.25\text{ V}$ to $12\text{ V}$ , $I_L = 0.1\text{ mA}$ to $200\text{ mA}$ , $T_A = 25^{\circ}\text{C}$	-0.7		+0.7	%
		$V_{IN} = V_{OUTNOM} + 0.25\text{ V}$ to $12\text{ V}$ , $I_L = 0.1\text{ mA}$ to $150\text{ mA}$ , $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	-1.4		+1.4	%
		$V_{IN} = V_{OUTNOM} + 0.25\text{ V}$ to $12\text{ V}$ , $I_L = 0.1\text{ mA}$ to $200\text{ mA}$ , $T_A = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	-1.4		+1.4	%
LINE REGULATION	$\Delta V_O/\Delta V_{IN}$	$V_{IN} = V_{OUTNOM} + 0.25\text{ V}$ to $12\text{ V}$ , $T_A = 25^{\circ}\text{C}$		0.04		mV/V
LOAD REGULATION	$\Delta V_O/\Delta I_L$	$I_L = 0.1\text{ mA}$ to $200\text{ mA}$ , $T_A = 25^{\circ}\text{C}$		0.04		mV/mA
GROUND CURRENT	$I_{GND}$	$I_L = 200\text{ mA}$ , $T_A = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		1.6	4.0	mA
		$I_L = 150\text{ mA}$		1.2	3.1	mA
		$I_L = 50\text{ mA}$		0.4	1.1	mA
		$I_L = 0.1\text{ mA}$		34	50	$\mu\text{A}$
GROUND CURRENT IN DROPOUT	$I_{GND}$	$V_{IN} = V_{OUTNOM} - 100\text{ mV}$ , $I_L = 0.1\text{ mA}$		37	55	$\mu\text{A}$
DROPOUT VOLTAGE	$V_{DROP}$	$V_{OUT} = 98\%$ of $V_{OUTNOM}$				
		$I_L = 200\text{ mA}$ , $T_A = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		140	230	mV
		$I_L = 150\text{ mA}$		110	170	mV
		$I_L = 10\text{ mA}$		42	60	mV
		$I_L = 1\text{ mA}$		25	50 <sup>1</sup>	mV
PEAK LOAD CURRENT	$I_{LDPK}$	$V_{IN} = V_{OUTNOM} + 1\text{ V}$		300		mA
OUTPUT NOISE <sup>2</sup>	$V_{NOISE}$	$f = 10\text{ Hz}$ to $100\text{ kHz}$ , $C_L = 10\text{ }\mu\text{F}$ , $I_L = 200\text{ mA}$ , $C_{NR} = 10\text{ nF}$ , $V_{OUT} = 3\text{ V}$		47		$\mu\text{V rms}$
		$f = 10\text{ Hz}$ to $100\text{ kHz}$ , $C_L = 10\text{ }\mu\text{F}$ , $I_L = 200\text{ mA}$ , $C_{NR} = 0\text{ nF}$ , $V_{OUT} = 3\text{ V}$		95		$\mu\text{V rms}$
SHUTDOWN THRESHOLD	$V_{THSD}$	On	2.0			V
		Off			0.4	V
SHUTDOWN PIN INPUT CURRENT	$I_{SD}$	$V_{IN} = 12\text{ V}$ , $0\text{ V} < \overline{SD} \leq 12\text{ V}$		1.9	9	$\mu\text{A}$
		$0\text{ V} < \overline{SD} \leq 5\text{ V}$		1.4	6	$\mu\text{A}$
GROUND CURRENT IN SHUTDOWN MODE	$I_{GNDSD}$	$\overline{SD} = 0\text{ V}$ , $V_{IN} = 12\text{ V}$		0.01	2	$\mu\text{A}$
OUTPUT CURRENT IN SHUTDOWN MODE	$I_{OSD}$	$T_A = 25^{\circ}\text{C}$ at $V_{IN} = 12\text{ V}$			1	$\mu\text{A}$
		$T_A = 85^{\circ}\text{C}$ at $V_{IN} = 12\text{ V}$			2	$\mu\text{A}$
ERROR PIN OUTPUT LEAKAGE	$I_{EL}$	$V_{EO} = 5\text{ V}$			1	$\mu\text{A}$
ERROR PIN OUTPUT LOW VOLTAGE	$V_{EOL}$	$I_{SINK} = 400\text{ }\mu\text{A}$		0.19	0.40	V

<sup>1</sup> Application stable with no load.

<sup>2</sup> See Figure 21 and Applications Information section for additional information.

## ADP3330-2.5

At  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{IN} = 7\text{ V}$ ,  $C_{IN} = 0.47\text{ }\mu\text{F}$ ,  $C_{OUT} = 0.47\text{ }\mu\text{F}$ , unless otherwise noted. Ambient temperature of  $+85^{\circ}\text{C}$  corresponds to a junction temperature of  $+125^{\circ}\text{C}$  under typical full load test conditions. Application stable with no load.

Table 2.

Parameter	Symbol	Test Conditions/Conditions	Min	Typ	Max	Unit
OUTPUT VOLTAGE ACCURACY	$V_{OUT}$	$V_{IN} = 2.9\text{ V}$ to $12\text{ V}$ , $I_L = 0.1\text{ mA}$ to $200\text{ mA}$ , $T_A = 25^{\circ}\text{C}$	-0.7		+0.7	%
		$V_{IN} = 2.9\text{ V}$ to $12\text{ V}$ , $I_L = 0.1\text{ mA}$ to $150\text{ mA}$ , $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	-1.4		+1.4	%
		$V_{IN} = 2.9\text{ V}$ to $12\text{ V}$ , $I_L = 0.1\text{ mA}$ to $200\text{ mA}$ , $T_A = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$	-1.4		+1.4	%
LINE REGULATION	$\Delta V_O/\Delta V_{IN}$	$V_{IN} = 2.9\text{ V}$ to $12\text{ V}$ , $T_A = 25^{\circ}\text{C}$		0.04		mV/V
LOAD REGULATION	$\Delta V_O/\Delta I_L$	$I_L = 0.1\text{ mA}$ to $200\text{ mA}$ , $T_A = 25^{\circ}\text{C}$		0.04		mV/mA
GROUND CURRENT	$I_{GND}$	$I_L = 200\text{ mA}$ , $T_A = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		1.6	4.0	mA
		$I_L = 150\text{ mA}$		1.2	3.1	mA
		$I_L = 50\text{ mA}$		0.4	1.1	mA
		$I_L = 0.1\text{ mA}$		34	50	$\mu\text{A}$
GROUND CURRENT IN DROPOUT	$I_{GND}$	$V_{IN} = V_{OUTNOM} - 100\text{ mV}$ , $I_L = 0.1\text{ mA}$		37	55	$\mu\text{A}$
DROPOUT VOLTAGE	$V_{DROP}$	$V_{OUT} = 98\%$ of $V_{OUTNOM}$				
		$I_L = 200\text{ mA}$ , $T_A = -20^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		140	230	mV
		$I_L = 150\text{ mA}$		110	170	mV
		$I_L = 10\text{ mA}$		42	60	mV
		$I_L = 1\text{ mA}$		25	50 <sup>1</sup>	mV
PEAK LOAD CURRENT	$I_{LDPK}$	$V_{IN} = V_{OUTNOM} + 1\text{ V}$		300		mA
OUTPUT NOISE <sup>2</sup>	$V_{NOISE}$	$f = 10\text{ Hz}$ to $100\text{ kHz}$ , $C_L = 10\text{ }\mu\text{F}$ , $I_L = 200\text{ mA}$ , $C_{NR} = 10\text{ nF}$ , $V_{OUT} = 3\text{ V}$		47		$\mu\text{V rms}$
		$f = 10\text{ Hz}$ to $100\text{ kHz}$ , $C_L = 10\text{ }\mu\text{F}$ , $I_L = 200\text{ mA}$ , $C_{NR} = 0\text{ nF}$ , $V_{OUT} = 3\text{ V}$		95		$\mu\text{V rms}$
SHUTDOWN THRESHOLD	$V_{THSD}$	On	2.0			V
		Off			0.4	V
SHUTDOWN PIN INPUT CURRENT	$I_{SD}$	$V_{IN} = 12\text{ V}$ , $0\text{ V} < \overline{SD} \leq 12\text{ V}$		1.9	9	$\mu\text{A}$
		$0\text{ V} < \overline{SD} \leq 5\text{ V}$		1.4	6	$\mu\text{A}$
GROUND CURRENT IN SHUTDOWN MODE	$I_{GNDSD}$	$\overline{SD} = 0\text{ V}$ , $V_{IN} = 12\text{ V}$		0.01	2	$\mu\text{A}$
OUTPUT CURRENT IN SHUTDOWN MODE	$I_{OSD}$	$T_A = 25^{\circ}\text{C}$ at $V_{IN} = 12\text{ V}$			1	$\mu\text{A}$
		$T_A = 85^{\circ}\text{C}$ at $V_{IN} = 12\text{ V}$			2	$\mu\text{A}$
ERROR PIN OUTPUT LEAKAGE	$I_{EL}$	$V_{EO} = 5\text{ V}$			1	$\mu\text{A}$
ERROR PIN OUTPUT LOW VOLTAGE	$V_{EOL}$	$I_{SINK} = 400\text{ }\mu\text{A}$		0.19	0.40	V

<sup>1</sup> Application stable with no load.<sup>2</sup> See Figure 21 and Applications Information section for additional information.

## ABSOLUTE MAXIMUM RATINGS

Table 3.

Parameter	Rating
Input Supply Voltage	–0.3 V to +16 V
Shutdown Input Voltage	–0.3 V to +16 V
Power Dissipation	Internally limited
Operating Ambient Temperature Range	–40°C to +85°C
Operating Junction Temperature Range	–40°C to +125°C
$\theta_{JA}$ (4-Layer Board)	165°C/W
$\theta_{JA}$ (2-Layer Board)	190°C/W
Storage Temperature Range	–65°C to +150°C
Lead Temperature (not a range)	
(Soldering 10 seconds)	300°C
Vapor Phase (60 seconds)	215°C
Infrared (15 seconds)	220°C

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

### ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

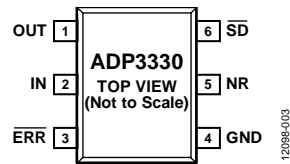


Figure 3. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	OUT	Output of the Regulator. Bypass to ground with a 0.47 $\mu$ F or larger capacitor.
2	IN	Regulator Input.
3	ERR	Open Collector Output. This pin goes low to indicate that the output is about to go out of regulation.
4	GND	Ground Pin.
5	NR	Noise Reduction Pin. This pin is used for further reduction of output noise (see the Applications Information section). Do not connect if this pin is not used.
6	SD	Active Low Shutdown Pin. Connect to ground to disable the regulator output. When shutdown is not used, this pin must be connected to the input pin.

## TYPICAL PERFORMANCE CHARACTERISTICS

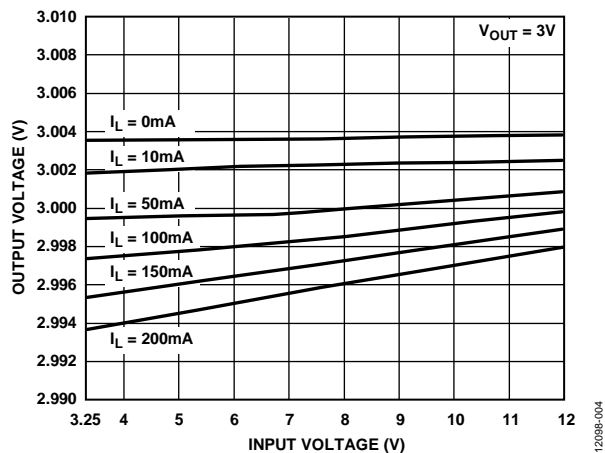


Figure 4. Line Regulation Output Voltage vs. Input Voltage

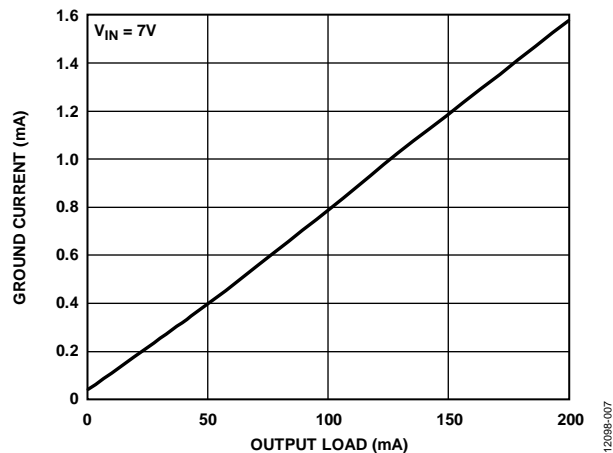


Figure 7. Ground Current vs. Output Current

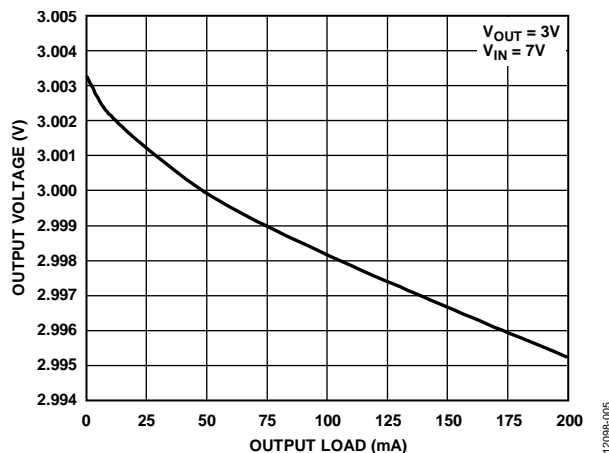


Figure 5. Output Voltage vs. Output Current

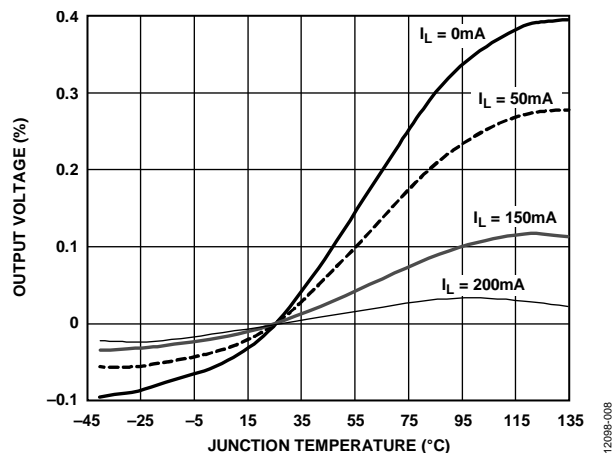


Figure 8. Output Voltage Variation Percent vs. Junction Temperature

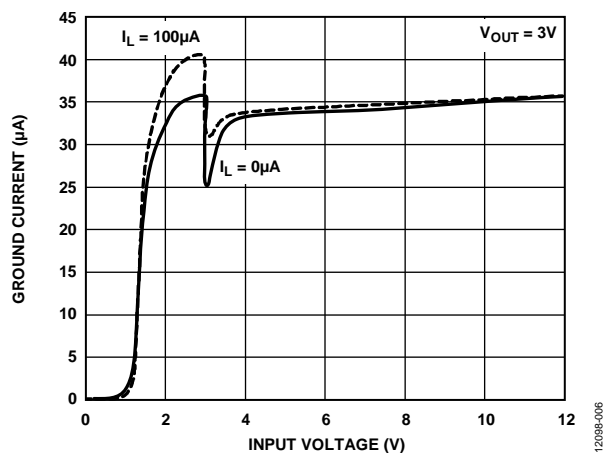


Figure 6. Ground Current vs. Input Voltage

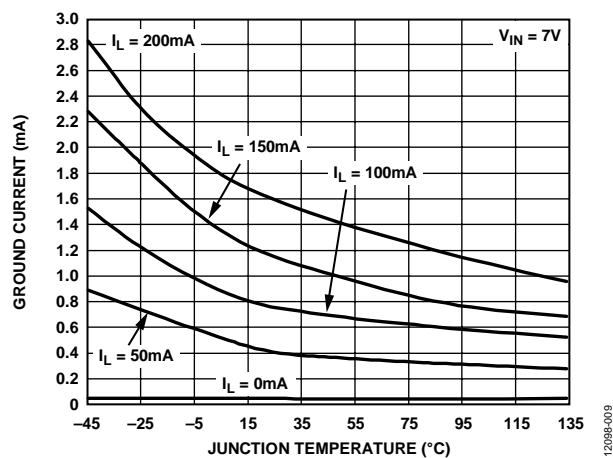


Figure 9. Ground Current vs. Junction Temperature



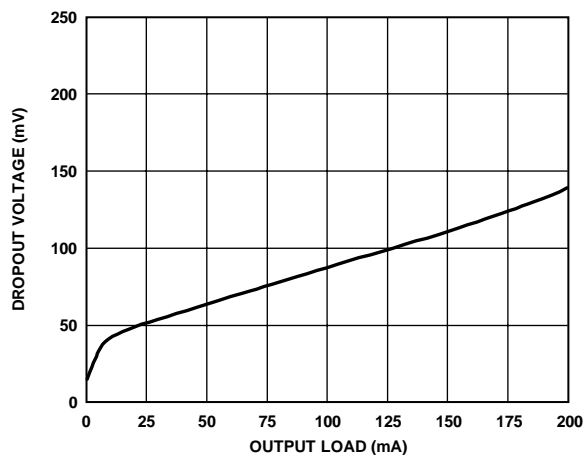


Figure 10. Dropout Voltage vs. Output Current

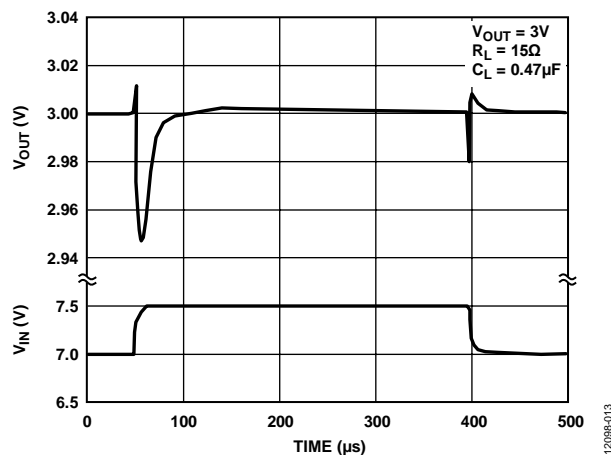
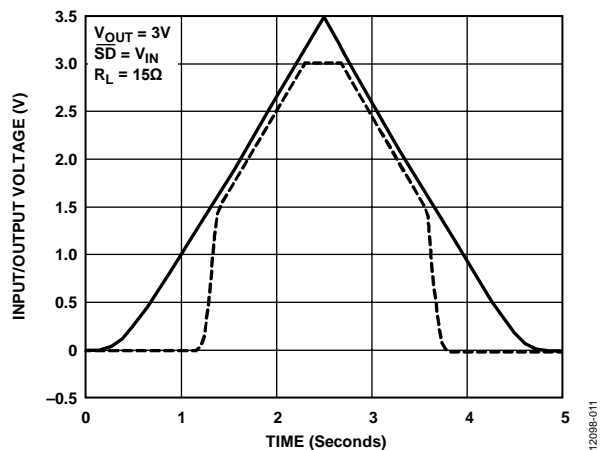
Figure 13. Line Transient Response,  $C_L = 0.47 \mu F$ 

Figure 11. Power-Up/Power-Down

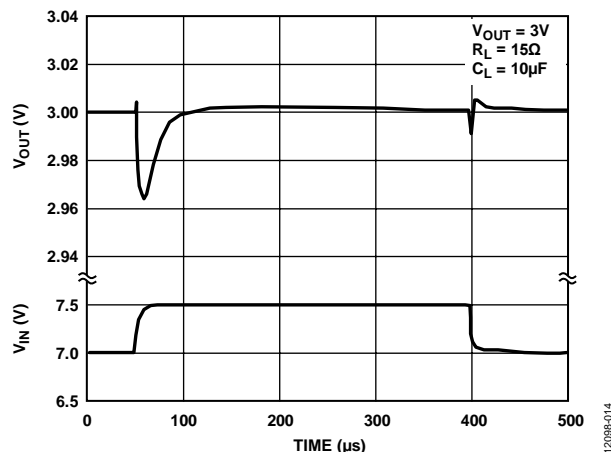
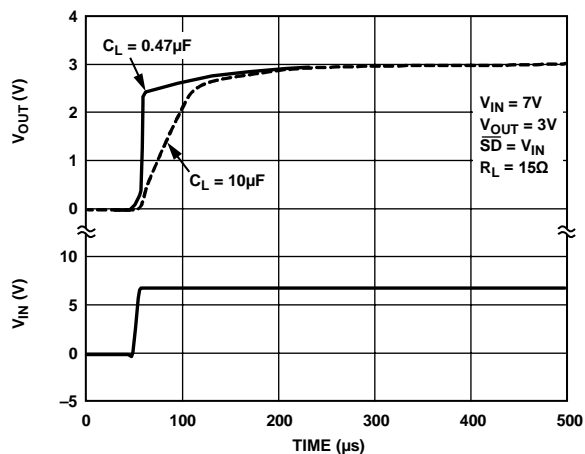
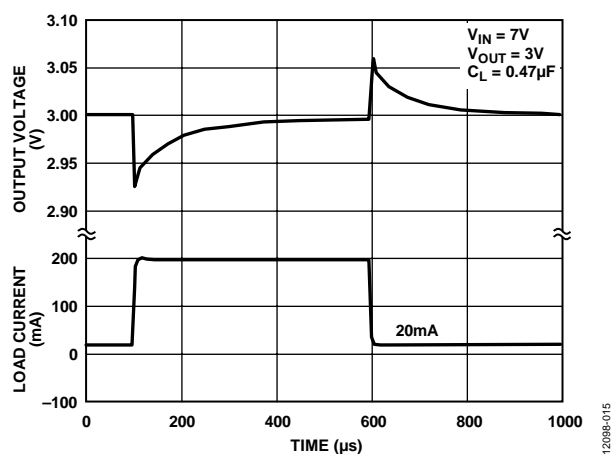
Figure 14. Line Transient Response,  $C_L = 10 \mu F$ 

Figure 12. Power-Up Response

Figure 15. Load Transient Response,  $C_L = 0.47 \mu F$

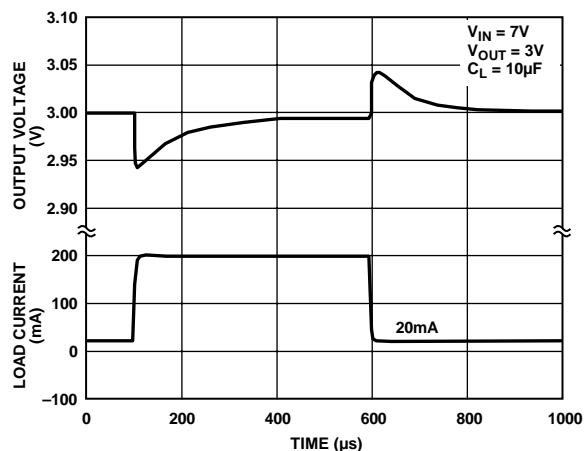
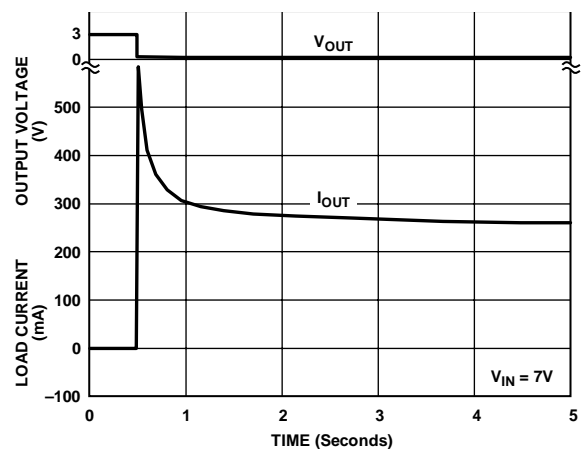
Figure 16. Load Transient Response,  $C_L = 10 \mu\text{F}$ 

Figure 17. Short-Circuit Current

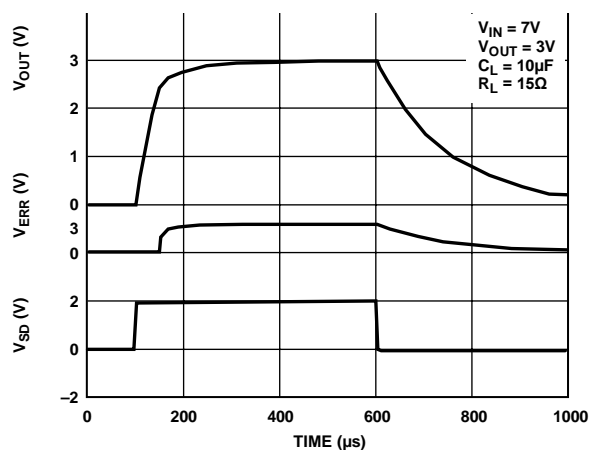


Figure 18. Turn On/Turn Off Response

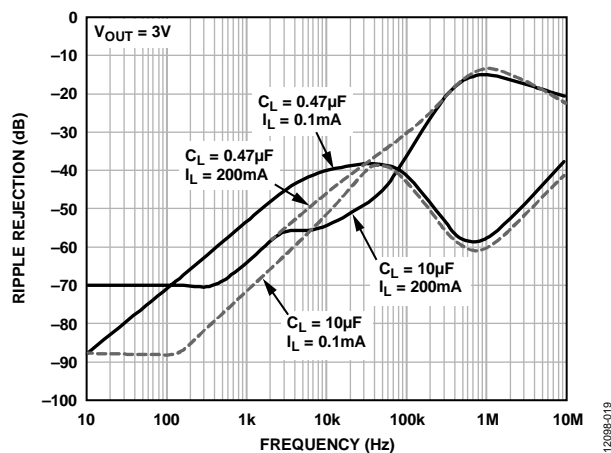


Figure 19. Power Supply Ripple Rejection vs. Frequency

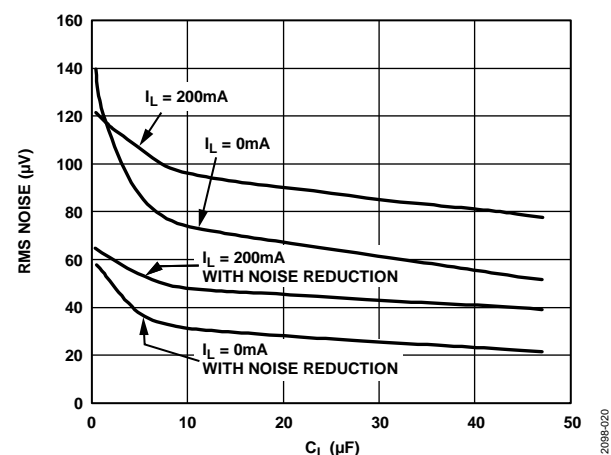
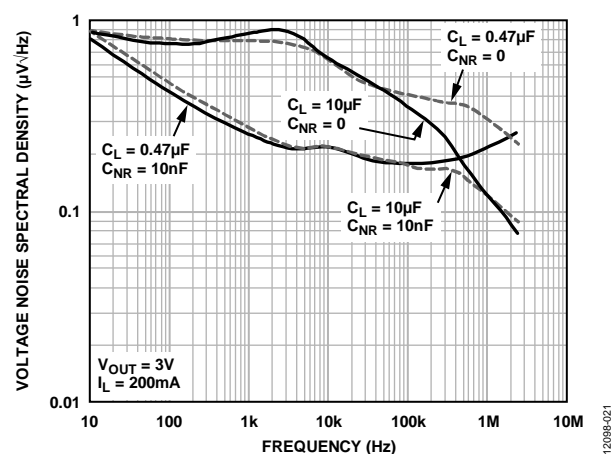
Figure 20. RMS Noise vs.  $C_L$  (10 Hz to 100 kHz)

Figure 21. Output Noise Density

## THEORY OF OPERATION

The anyCAP low dropout (LDO) [ADP3330](#) uses a single control loop for regulation and reference functions. The output voltage is sensed by a resistive voltage divider consisting of R1 and R2, which is varied to provide the available output voltage options. Feedback is taken from this network by way of a series diode (D1) and a second resistor divider (R3 and R4) to the input of an amplifier.

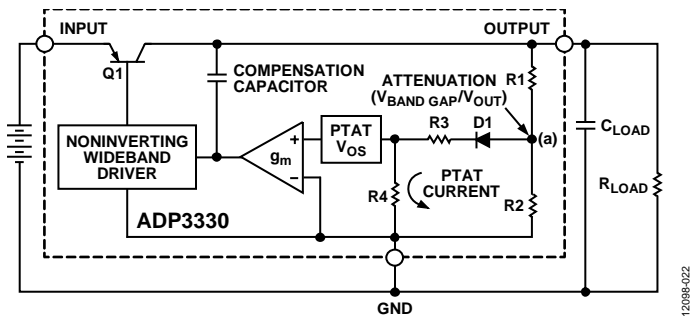


Figure 22. Functional Block Diagram

A very high gain error amplifier is used to control this loop. The amplifier is constructed in such a way that, at equilibrium, the amplifier produces a large, temperature proportional input offset voltage that is repeatable and very well controlled. The temperature proportional offset voltage is combined with the complementary diode voltage to form a virtual band gap voltage, implicit in the network, although it never appears explicitly in the circuit. Ultimately, this patented design makes it possible to control the loop with only one amplifier. This technique also improves the noise characteristics of the amplifier by providing more flexibility on the trade-off of noise sources that leads to a low noise design.

The R1, R2 divider is chosen in the same ratio as the band gap voltage to the output voltage. Although the R1, R2 resistor divider is loaded by the D1 diode and a second divider consisting of R3 and R4, the values are chosen to produce a temperature stable output. This unique arrangement specifically corrects the loading of the divider so that the typical error resulting from base current loading in conventional circuits is avoided.

The patented amplifier controls a new and unique noninverting driver that drives the pass transistor, Q1. The use of this noninverting driver enables the frequency compensation to include the load capacitor in a pole splitting arrangement to achieve reduced sensitivity to the value, type, and ESR of the load capacitance.

Most LDOs place strict requirements on the range of ESR values for the output capacitor because they are difficult to stabilize, due to the uncertainty of load capacitance and resistance. Moreover, the ESR value required to keep conventional LDOs stable changes depending on load and temperature. These ESR limitations make designing with LDOs more difficult because of their unclear specifications and extreme variations over temperature.

The [ADP3330](#) anyCAP LDO overcomes these limitations. It can be used with virtually any good quality capacitor, with no constraint on the minimum ESR. The innovative design allows the circuit to be stable with just a small 0.47  $\mu\text{F}$  capacitor on the output. Additional advantages of the pole splitting scheme include superior line noise rejection and very high regulator gain, which leads to excellent line and load regulation. An impressive  $\pm 1.4\%$  accuracy is guaranteed over line, load and temperature.

Additional features of the circuit include current limit, thermal shutdown, and noise reduction. Compared to standard solutions that give warning after the output has lost regulation, the [ADP3330](#) provides improved system performance by enabling the `ERR` pin to give warning just before the device loses regulation.

When the temperature of the chip rises to more than 165°C, the circuit activates a soft thermal shutdown, indicated by a signal low on the **ERR** pin, to reduce the current to a safe level.

## APPLICATIONS INFORMATION

### CAPACITOR SELECTION

#### Output Capacitors

As with any micropower device, output transient response is a function of the output capacitance. The ADP3330 is stable with a wide range of capacitor values, types, and ESR (anyCAP). A capacitor as low as 0.47  $\mu\text{F}$  is all that is needed for stability; larger capacitors can be used if high output current surges are anticipated. The ADP3330 is stable with extremely low ESR capacitors ( $\text{ESR} \approx 0$ ), such as MLCC or OSCON. Note that the effective capacitance of some capacitor types may fall less than the minimum at cold temperature. Ensure that the capacitor provides more than 0.47  $\mu\text{F}$  at minimum temperature.

#### Input Bypass Capacitor

An input bypass capacitor is not strictly required, but it is advisable in any application involving long input wires or high source impedance. Connecting a 0.47  $\mu\text{F}$  capacitor from IN to GND reduces the sensitivity of the circuit to printed circuit board (PCB) layout. If a larger value output capacitor is used, a larger value input capacitor is also recommended.

### NOISE REDUCTION

A noise reduction capacitor ( $C_{\text{NR}}$ ) can be used to further reduce the noise by 6 dB to 10 dB (see Figure 23). Low leakage capacitors in the 10 pF to 500 pF range provide the best performance. Carefully connect to this node to avoid noise pickup from external sources because the noise reduction pin (NR) is internally connected to a high impedance node. The pad connected to this pin must be as small as possible and long PCB traces are not recommended.

When adding a noise reduction capacitor, use the following guidelines:

- Maintain a minimum load current of 1 mA when not in shutdown.
- For  $C_{\text{NR}}$  values greater than 500 pF, add a 100 k $\Omega$  series resistor ( $R_{\text{NR}}$ ).

It is important to note that as  $C_{\text{NR}}$  increases, the turn on time is delayed. When  $C_{\text{NR}}$  values are greater than 1 nF, this delay may be in the order of several milliseconds.

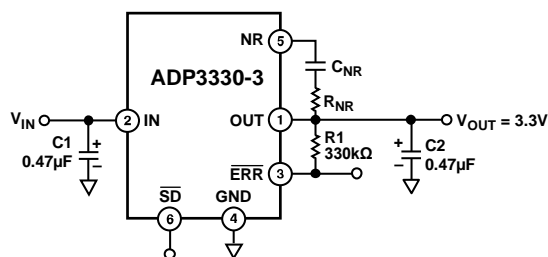


Figure 23. Noise Reduction Circuit

### CHIP-ON-LEAD PACKAGE

The ADP3330 uses a Chip-on-Lead package design (protected by U.S. Patent 5929514 A) to ensure the best thermal performance in the 6-lead SOT-23 footprint. In a standard 6-lead SOT-23 package, the majority of the heat flows out of the ground pin. The Chip-on-Lead package uses an electrically isolated die attachment that allows all pins to contribute to the heat conduction. This technique reduces the thermal resistance to 190°C/W on a 2-layer board as compared to >230°C/W for a standard SOT-23 lead frame. Figure 24 and Figure 25 show the difference between the standard 6-lead SOT-23 and the Chip-on-Lead lead frames.

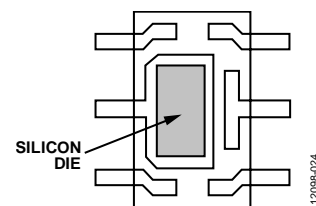


Figure 24. Normal 6-Lead SOT-23 Package

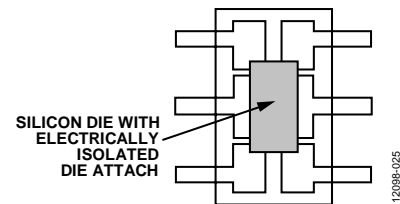


Figure 25. Thermally Enhanced, Chip-on-Lead Package

### THERMAL OVERLOAD PROTECTION

The ADP3330 is protected against damage due to excessive power dissipation by its thermal overload protection circuit, which limits the die temperature to a maximum of 165°C. Under extreme conditions, (that is, high ambient temperature and power dissipation) where die temperature starts to rise more than 165°C, the output current decreases until the die temperature has dropped to a safe level. The output current is restored when the die temperature is reduced.

Current and thermal limit protections protect the device against accidental overload conditions. For normal operation, device power dissipation must be externally limited so that the junction temperatures do not exceed 125°C.

## CALCULATING JUNCTION TEMPERATURE

Device power dissipation is calculated as follows:

$$P_D = (V_{IN} - V_{OUT}) I_{LOAD} + (V_{IN}) I_{GND}$$

where:

$I_{LOAD}$  and  $I_{GND}$  are load current and ground current.

$V_{IN}$  and  $V_{OUT}$  are input and output voltages, respectively.

Assuming  $I_{LOAD} = 200$  mA,  $I_{GND} = 4$  mA,  $V_{IN} = 4.2$  V, and  $V_{OUT} = 3.0$  V, the device power dissipation is the following:

$$P_D = (4.2 - 3.0) 200 \text{ mA} + 4.2 (4 \text{ mA}) = 257 \text{ mW}$$

The proprietary package used in the ADP3330 has a thermal resistance of  $165^\circ\text{C}/\text{W}$ , significantly lower than the standard 6-lead SOT-23 package. Assuming a 4-layer board, the junction temperature rise above ambient temperature is approximately equal to

$$\Delta T_{JA} = 0.257 \text{ W} \times 165^\circ\text{C}/\text{W} = 42.4^\circ\text{C}$$

To limit the maximum junction temperature to  $125^\circ\text{C}$ , maximum allowable ambient temperature is

$$T_{A\text{ MAX}} = 125^\circ\text{C} - 42.4^\circ\text{C} = 82.6^\circ\text{C}$$

## PRINTED CIRCUIT BOARD (PCB) LAYOUT CONSIDERATIONS

All packages rely on the traces of the PCB to conduct heat away from the package.

In standard packages, the dominant component of the heat resistance path is the plastic between the die attach pad and the individual leads. In typical thermally enhanced packages, one or more of the leads are fused to the die attach pad, significantly decreasing this component. To make the improvement meaningful, however, a significant copper area on the PCB must be attached to these fused pins.

The patented chip-on-lead frame design of the ADP3330 uniformly minimizes the value of the dominant portion of the thermal resistance. It ensures that heat is conducted away by all of the package pins and yields a very low  $165^\circ\text{C}/\text{W}$  thermal resistance for the 6-lead SOT-23 package. Low thermal resistance is achieved without any special board layout requirements, just the normal traces connected to the leads, and yields a 17% improvement in heat dissipation capability as compared to a standard 6-lead SOT-23 package. The thermal resistance can be decreased by approximately an additional 10% by attaching a few square cm of copper area to the  $V_{IN}$  pin of the ADP3330 package.

It is not recommended to use solder mask or silkscreen on the PCB traces adjacent to the pins of the ADP3330 because it increases the junction to ambient thermal resistance of the package.

## ERROR FLAG DROPOUT DETECTOR

The ADP3330 maintains its output voltage over a wide range of load, input voltage, and temperature conditions. If the output is about to lose regulation by reducing the supply voltage less than the combined regulated output and dropout voltages, the ERR flag is activated. The  $\overline{\text{ERR}}$  output is an open collector that is driven low.

When the  $\overline{\text{ERR}}$  output is set, the hysteresis of the  $\overline{\text{ERR}}$  flag keeps the output low until a small margin of the operating range is restored either by raising the supply voltage or reducing the load.

## SHUTDOWN MODE

Applying a TTL high signal to the shutdown ( $\overline{\text{SD}}$ ) pin, or tying the SD pin to the input pin, turns the output on. Pulling the  $\overline{\text{SD}}$  pin down to 0.4 V or below, or tying the  $\overline{\text{SD}}$  pin to ground, turns the output off (we do not do all caps for emphasis). In shutdown mode, the ground current is reduced to much less than 1  $\mu\text{A}$ .

## LOW POWER, LOW DROPOUT APPLICATIONS

The ADP3330 is well suited for applications such as cell phone handsets that require low ground current and low dropout voltage features. The ADP3330 typically draws 34  $\mu\text{A}$  under light load situations (that is, load current = 100  $\mu\text{A}$ ), which results in low power consumption when the cell phone is in standby mode.

Figure 26 shows an application in which the ADP3330 is used in a handset to provide 2.75 V nominal output voltage. The cell phone is powered from a 3 cell NiCd or 1 cell Li-Ion battery. The ADP3330 guarantees an accuracy of 1.4%, even when the input/output differential is merely 250 mV (worst case). Therefore, the voltage output is regulated and within specification even when the battery voltage has reached its end of discharge voltage of 3 V. The output voltage never falls less than 2.7 V, even under worst case load and temperature conditions. The low dropout feature coupled with the high accuracy of the ADP3330 ensures that the system is reliably powered until the end of the life of the battery, which results in increased system talk time.

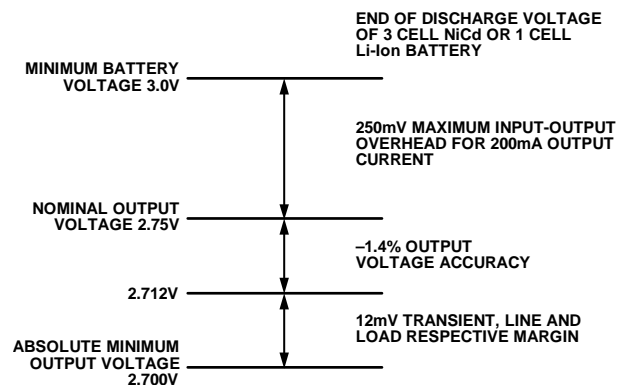


Figure 26. LDO Budgeting for a 3 Cell NiCd/1 Cell Li-Ion Supply

## APPLICATION CIRCUITS

### CROSSOVER SWITCH

The circuit in Figure 27 shows how two ADP3330s can be used to form a mixed supply voltage system. The output switches between two different levels selected by an external digital input. Output voltages can be any combination of voltages that are included in the Ordering Guide.

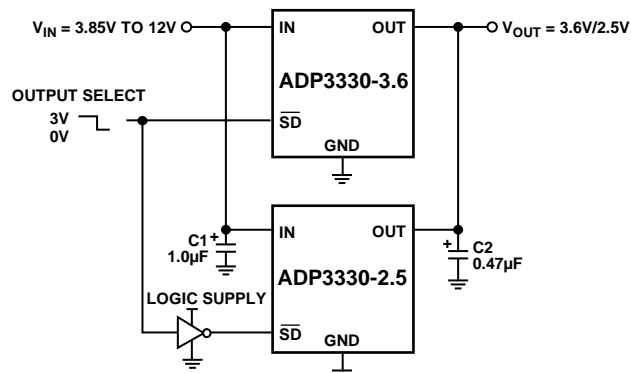
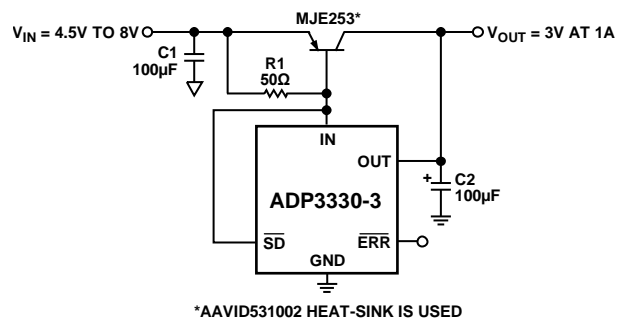


Figure 27. Crossover Switch

12098-027

### HIGHER OUTPUT CURRENT

The ADP3330 can source up to 200 mA at room temperature without any heat-sink, or pass transistor. If higher current is needed, an appropriate pass transistor can be used, as in Figure 28, to increase the output current to 1 A.

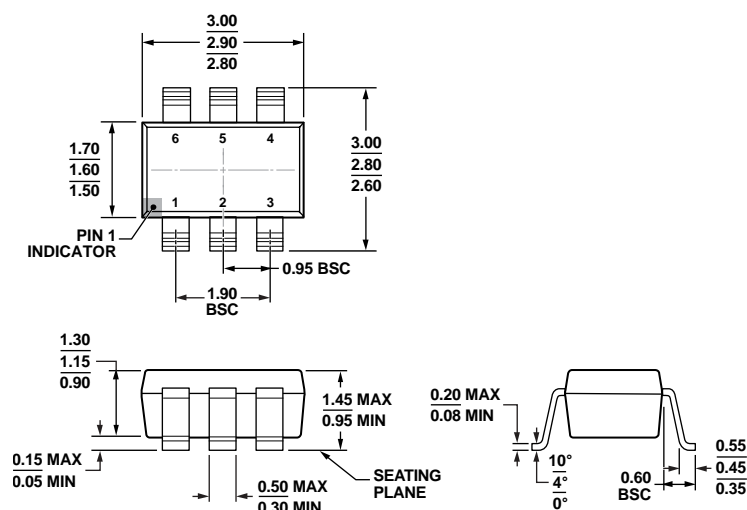


\*AAVID531002 HEAT-SINK IS USED

Figure 28. High Output Current Linear Regulator

12098-028

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-178-AB

Figure 29. 6-Lead Small Outline Transistor Package [SOT-23]  
RJ-6

Dimensions shown in millimeters

12-16-2008-A

## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	Voltage Output (V)	Package Description	Package Option <sup>2</sup>	Branding
ADP3330ARTZ-2.5-R7	–40°C to +85°C	2.5	6-Lead SOT-23	RJ-6	L1B
ADP3330ARTZ-2.75R7	–40°C to +85°C	2.75	6-Lead SOT-23	RJ-6	L2B
ADP3330ARTZ-2.75RL	–40°C to +85°C	2.75	6-Lead SOT-23	RJ-6	L2B
ADP3330ARTZ-2.85R7	–40°C to +85°C	2.85	6-Lead SOT-23	RJ-6	L3B
ADP3330ARTZ-3-RL7	–40°C to +85°C	3.0	6-Lead SOT-23	RJ-6	L4B
ADP3330ARTZ3.3-RL7	–40°C to +85°C	3.3	6-Lead SOT-23	RJ-6	L5B
ADP3330ARTZ-3.6-R7	–40°C to +85°C	3.6	6-Lead SOT-23	RJ-6	L6B
ADP3330ARTZ-5-RL7	–40°C to +85°C	5.0	6-Lead SOT-23	RJ-6	L8B

<sup>1</sup> Z = RoHS Compliant Part.

<sup>2</sup> Contact the factory for the availability of other output voltage options.

## NOTES



**NOTES**